Technical Data Data Sheet 3204, Rev. A

## 440CNQ030 SCHOTTKY RECTIFIER

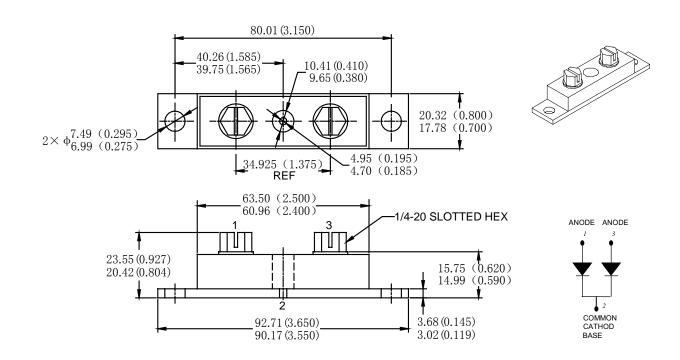
## **Applications:**

• Switching power supply • Free-Wheeling diodes • Reverse battery protection • Converters

### Features:

- 150°C T<sub>J</sub> operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability

### Mechanical Dimensions: In Inches / mm



## PRM4(Non-Isolated)

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# Data Sheet 3204, Rev. A Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	$V_{RWM}$	-		30	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> = 95 °C,	220	per leg	Α
Current		rectangular wave form	440	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	3600		А
Non-Repetitive Avalanche Energy (per leg)	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 44 A, L = 0.20 mH		198	mJ
Repetitive Avalanche Current (per leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		44	А

## **Electrical Characteristics:**

Characteristics	<b>Symbol</b>	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 220 A, Pulse, T <sub>J</sub> = 25 °C	0.50	V
(per leg) *		@ 440 A, Pulse, T <sub>J</sub> = 25 °C	0.60	
	$V_{F2}$	@ 220 A, Pulse, T <sub>J</sub> = 125 °C	0.41	V
		@ 440 A, Pulse, T <sub>J</sub> = 125 °C	0.52	
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_R, T_J = 25  ^{\circ}\text{C}$	20	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R, T_J = 125  ^{\circ}\text{C}$	1120	mA
Max. Junction Capacitance	$C_T$	$@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$	14800	рF
(per leg)		f <sub>SIG</sub> = 1 MHz		
Typical Series Inductance	L <sub>S</sub>	Measured lead to lead 5 mm	5.0	nΗ
(per leg)		from package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

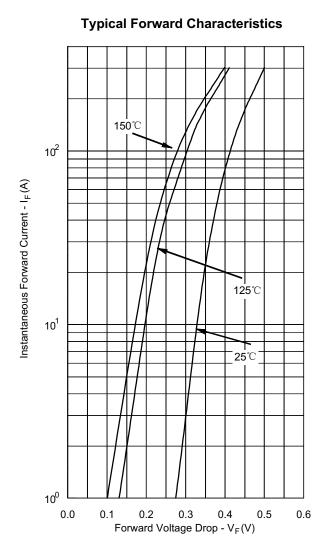
# **Thermal-Mechanical Specifications:**

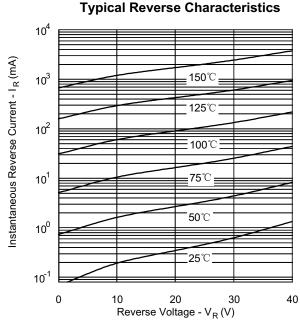
Characteristics	Symbol	Condition	Specification		Units	
Max. Junction Temperature	TJ	-	-55 to +150		°C	
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150		°C	
Maximum Thermal Resistance Junction to Case (per leg)	R <sub>0JC</sub>	DC operation	0.20		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.10		°C/W	
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.10		°C/W	
Approximate Weight	wt	-	79		g	
Mounting Torque	T <sub>M</sub>	-	Mounting Torque Base Terminal Torque	24 (min) 35 (max) 35 (min) 46 (max)	Kg-cm	
Case Style	PRM4 Non-Isolated					

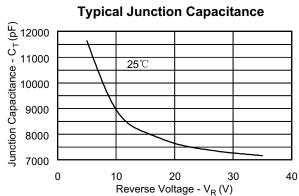
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